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[Understanding Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	27696
Total RAM Bits	1130496
Number of I/O	195
Number of Gates	-
Voltage - Supply	1.14V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	400-LFBGA
Supplier Device Package	400-VFBGA (17x17)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/m2gl025t-vfg400i



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2.3.5.7 2.5 V LVC MOS

LVC MOS 2.5 V is a general standard for 2.5 V applications and is supported in IGLOO2 FPGA and SmartFusion2 SoC FPGAs that are in compliance with the JEDEC specification JESD8-5A.

Minimum and Maximum DC/AC Input and Output Levels Specification

Table 38 • LVC MOS 2.5 V DC Recommended DC Operating Conditions

Parameter	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{DDI}	2.375	2.5	2.625	V

Table 39 • LVC MOS 2.5 V DC Input Voltage Specification

Parameter	Symbol	Min	Max	Unit
DC input logic high (for MSIOD and DDRIO I/O banks)	V_{IH} (DC)	1.7	2.625	V
DC input logic high (for MSIO I/O bank)	V_{IH} (DC)	1.7	3.45	V
DC input logic low	V_{IL} (DC)	-0.3	0.7	V
Input current high ¹	I_{IH} (DC)			
Input current low ¹	I_{IL} (DC)			

1. See [Table 24](#), page 22.

Table 40 • LVC MOS 2.5 V DC Output Voltage Specification

Parameter	Symbol	Min	Max	Unit
DC output logic high	V_{OH} ¹	$V_{DDI} - 0.4$	-	V
DC output logic low	V_{OL} ²		0.4	V

1. The VOH/VOL test points selected ensure compliance with LVC MOS 2.5 V JEDEC8-5A requirements.

Table 41 • LVC MOS 2.5 V AC Minimum and Maximum Switching Speed

Parameter	Symbol	Max	Unit	Conditions
Maximum data rate (for DDRIO I/O bank)	D_{MAX}	400	Mbps	AC loading: 17 pF load, maximum drive/slew
Maximum data rate (for MSIO I/O bank)	D_{MAX}	410	Mbps	AC loading: 17 pF load, maximum drive/slew
Maximum data rate (for MSIOD I/O bank)	D_{MAX}	420	Mbps	AC loading: 17 pF load, maximum drive/slew

Table 42 • LVC MOS 2.5 V AC Calibrated Impedance Option

Parameter	Symbol	Typ	Unit
Supported output driver calibrated impedance (for DDRIO I/O bank)	R_{odt_cal}	75, 60, 50, 33, 25, 20	Ω

2.3.8.2 Output/Enable Register

Figure 8 • Timing Model for Output/Enable Register

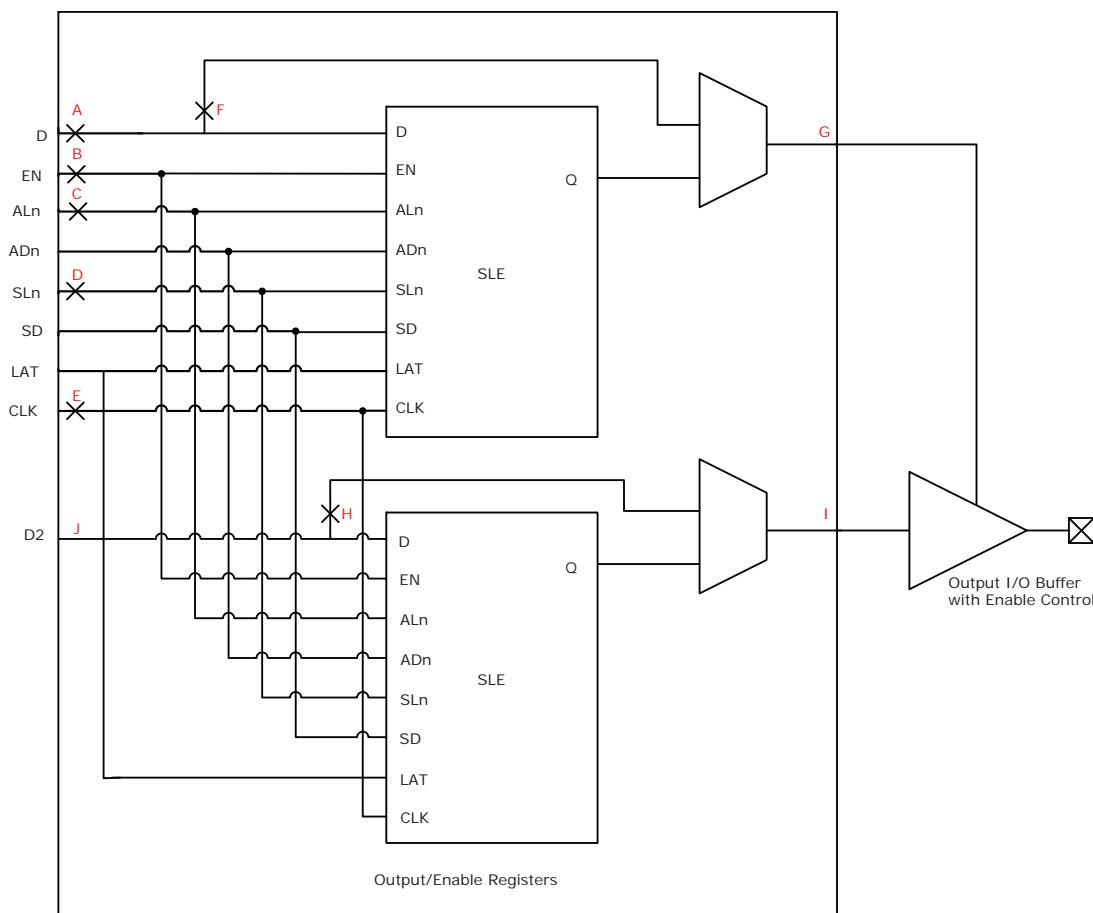


Table 243 • µSRAM (RAM1024x1) in 1024 × 1 Mode (continued)

Parameter	Symbol	-1		-Std	
		Min	Max	Min	Max
Read asynchronous reset recovery time (pipelined clock)	T _{RSTREC}	0.507		0.597	ns
Read asynchronous reset recovery time (non-pipelined clock)		0.236		0.278	ns
Read asynchronous reset to output propagation delay (with pipelined register enabled)	T _{R2Q}		0.83	0.98	ns
Read synchronous reset setup time	T _{SRSTSU}	0.271		0.319	ns
Read synchronous reset hold time	T _{SRSTHD}	0.061		0.071	ns
Write clock period	T _{CCY}	4		4	ns
Write clock minimum pulse width high	T _{CCLKMPWH}	1.8		1.8	ns
Write clock minimum pulse width low	T _{CCLKMPWL}	1.8		1.8	ns
Write block setup time	T _{BLKCSU}	0.404		0.476	ns
Write block hold time	T _{BLKCHD}	0.007		0.008	ns
Write input data setup time	T _{DINCSU}	0.003		0.004	ns
Write input data hold time	T _{DINCHD}	0.137		0.161	ns
Write address setup time	T _{ADDRCSU}	0.088		0.104	ns
Write address hold time	T _{ADDRCHD}	0.247		0.29	ns
Write enable setup time	T _{WECSU}	0.397		0.467	ns
Write enable hold time	T _{WECHD}	-0.03		-0.03	ns
Maximum frequency	F _{MAX}		250	250	MHz

2.3.13 Programming Times

The following tables list the programming times in typical conditions when T_J = 25 °C, V_{DD} = 1.2 V. External SPI flash part# AT25DF641-s3H is used during this measurement.

Table 244 • JTAG Programming (Fabric Only)

M2S/M2GL Device	Image size Bytes	Program	Verify	Unit
005	302672	22	10	Sec
010	568784	28	18	Sec
025	1223504	51	26	Sec
050	2424832	66	54	Sec
060	2418896	77	54	Sec
090	3645968	113	126	Sec
150	6139184	155	193	Sec

Table 245 • JTAG Programming (eNVM Only)

M2S/M2GL Device	Image size Bytes	Program	Verify	Unit
005	137536	39	4	Sec
010	274816	78	9	Sec
025	274816	78	9	Sec
050	278528	84	8	Sec
060	268480	76	8	Sec
090	544496	154	15	Sec
150	544496	155	15	Sec

Table 246 • JTAG Programming (Fabric and eNVM)

M2S/M2GL Device	Image size Bytes	Program	Verify	Unit
005	439296	59	11	Sec
010	842688	107	20	Sec
025	1497408	120	35	Sec
050	2695168	162	59	Sec
060	2686464	158	70	Sec
090	4190208	266	147	Sec
150	6682768	316	231	Sec

Table 247 • 2 Step IAP Programming (Fabric Only)

M2S/M2GL Device	Image size Bytes	Authenticate	Program	Verify	Unit
005	302672	4	17	6	Sec
010	568784	7	23	12	Sec
025	1223504	14	33	23	Sec
050	2424832	29	52	40	Sec
060	2418896	39	61	50	Sec
090	3645968	60	84	73	Sec
150	6139184	100	132	120	Sec

2.3.16 SRAM PUF

For more details on static random-access memory (SRAM) physical unclonable functions (PUF) services, see [AC434: Using SRAM PUF System Service in SmartFusion2 Application Note](#).

The following table lists the SRAM PUF in worst-case industrial conditions when $T_J = 100\text{ }^{\circ}\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 274 • SRAM PUF

Service	PUF Off		PUF On		Unit
	Typ	Max	Typ	Max	
Create activation code	709.1	746.4	754.4	762.5	ms
Delete activation code	1329.3	1399.3	1414.1	1429.3	ms
Create intrinsic keycode	656.6	691.1	698.5	706.0	ms
Create extrinsic keycode	656.6	691.1	698.5	706.0	ms
Get number of keys	1.3	1.4	1.4	1.4	ms
Export (Kc0, Kc1)	998.0	1050.5	1061.7	1073.1	ms
Export 2 keycodes	2020.2	2126.5	2149.2	2172.3	ms
Export 4 keycodes	3065.7	3227.0	3261.3	3296.4	ms
Export 8 keycodes	5101.0	5369.5	5426.6	5485.0	ms
Export 16 keycodes	9212.1	9697.0	9800.1	9905.5	ms
Import (Kc0, Kc1)	39.7	41.8	42.2	42.7	ms
Import 2 keycodes	50.1	52.7	53.3	53.9	ms
Import 4 keycodes	60.6	63.8	64.5	65.2	ms
Import 8 keycodes	80.9	85.1	86.1	87.0	ms
Import 16 keycodes	123.8	130.4	131.7	133.2	ms
Delete keycode	552.5	581.6	587.8	594.1	ms
Fetch key	31.4	33.0	33.4	33.7	ms
Fetch ecc key	20.0	21.1	21.3	21.5	ms
Get seed	2.0	2.1	2.2	2.2	ms

The following table lists the receiver pa in worst-case industrial conditions when $T_J = 100\text{ }^{\circ}\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 297 • Receiver Parameters

Symbol	Description	Min	Typ	Max	Unit
VRX-IN-PP-CC	Differential input peak-to-peak sensitivity (2.5 Gbps)	0.238		1.2	V
	Differential input peak-to-peak sensitivity (2.5 Gbps, de-emphasized)	0.219		1.2	V
	Differential input peak-to-peak sensitivity (5.0 Gbps)	0.300		1.2	V
	Differential input peak-to-peak sensitivity (5.0 Gbps, de-emphasized)	0.300		1.2	V
VRX-CM-AC-P	Input common mode range (AC coupled)			150	mV
ZRX-DIFF-DC	Differential input termination	80	100	120	Ω
REXT	External calibration resistor	1,188	1,200	1,212	Ω
CDR-LOCK-RST	CDR relock time from reset			15	μs
RLRX-DIFF	Return loss differential mode (2.5 Gbps)	-10			dB
	Return loss differential mode (5.0 Gbps)				
	0.05 GHz to 1.25 GHz	-10			dB
	1.25 GHz to 2.5 GHz	-8			dB
RLRX-CM	Return loss common mode (2.5 Gbps, 5.0 Gbps)	-6			dB
RX-CID ¹	CID limit PCIe Gen1/2			200	UI
VRX-IDLE-DET-DIFF-PP	Signal detect limit	65		175	mV

1. AC-coupled, BER = e^{-12} , using synchronous clock.

Table 298 • SerDes Protocol Compliance

Protocol	Maximum Data Rate (Gbps)	-1	-Std
PCIe Gen 1	2.5	Yes	Yes
PCIe Gen 2	5.0	Yes	
XAUI	3.125	Yes	
Generic EPCS	3.2	Yes	
Generic EPCS	2.5	Yes	Yes

Table 303 • I²C Characteristics (continued)

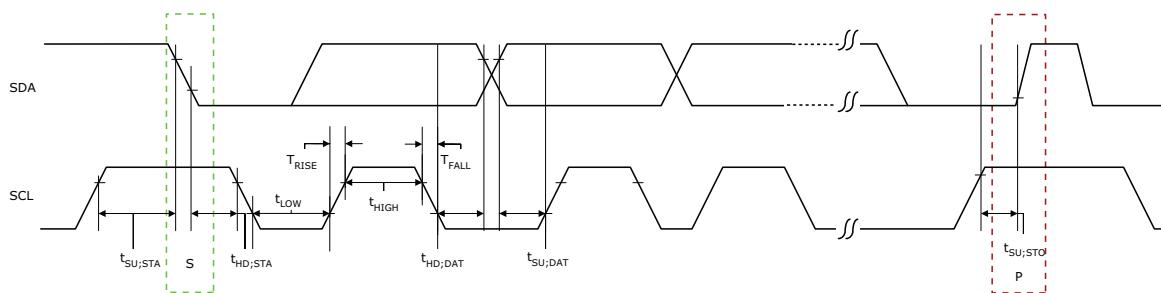
Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Maximum data rate	D _{MAX}			400	Kbps	Fast mode
				100	Kbps	Standard mode
Pulse width of spikes which must be suppressed by the input filter	T _{FILT}		50		ns	Fast mode

1. These values are provided for MSIO Bank-LVTTL 8 mA Low Drive at 25 °C, typical conditions. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the SoC Products Group website: <http://www.microsemi.com/soc/download/ibis/default.aspx>.
2. These maximum values are provided for information only. Minimum output buffer resistance values depend on V_{DDI}x, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located on the SoC Products Group website: <http://www.microsemi.com/soc/download/ibis/default.aspx>.
3. R(PULL-DOWN-MAX) = (VOLspec)/IOLspec.
4. R(PULL-UP-MAX) = (VDDImax–VOHspec)/IOHspec.

The following table lists the I²C switching characteristics in worst-case industrial conditions when T_J = 100 °C, V_{DD} = 1.14 V

Table 304 • I²C Switching Characteristics

Parameter	Symbol	-1		Std
		Min	Min	Unit
Low period of I ² C_x_SCL	T _{LOW}	1	1	PCLK cycles
High period of I ² C_x_SCL	T _{HIGH}	1	1	PCLK cycles
START hold time	T _{HD;STA}	1	1	PCLK cycles
START setup time	T _{SU;STA}	1	1	PCLK cycles
DATA hold time	T _{HD;DAT}	1	1	PCLK cycles
DATA setup time	T _{SU;DAT}	1	1	PCLK cycles
STOP setup time	T _{SU;STO}	1	1	PCLK cycles

Figure 21 • I²C Timing Parameter Definition

2.3.34 MMUART Characteristics

The following table lists the MMUART characteristics in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 308 • MMUART Characteristics

Parameter	Description	-1	-Std	Unit
FMMUART_REF_CLK	Internally sourced MMUART reference clock frequency.	166	142	MHz
BAUDMMUARTTx	Maximum transmit baud rate	10.375	8.875	Mbps
BAUDMMUARTRx	Maximum receive baud rate	10.375	8.875	Mbps

2.3.35 IGLOO2 Specifications

2.3.35.1 HPMS Clock Frequency

The following table lists the maximum frequency for HPMS main clock in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 309 • Maximum Frequency for HPMS Main Clock

Symbol	Description	-1	-Std	Unit
HPMS_CLK	Maximum frequency for the HPMS main clock	166	142	MHz

2.3.35.2 IGLOO2 Serial Peripheral Interface (SPI) Characteristics

This section describes the DC and switching of the SPI interface. Unless otherwise noted, all output characteristics given are for a 35 pF load on the pins and all sequential timing characteristics are related to SPI_0_CLK. For timing parameter definitions, see [Figure 23](#), page 131.

The following table lists the SPI characteristics in worst-case industrial conditions when $T_J = 100^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 310 • SPI Characteristics for All Devices

Symbol	Description	Min	Typ	Max	Unit	Conditions
SPIFMAX	Maximum operating frequency of SPI interface			20	MHz	
sp1	SPI_[0 1]_CLK minimum period					
	SPI_[0 1]_CLK = PCLK/2	12			ns	
	SPI_[0 1]_CLK = PCLK/4	24.1			ns	
	SPI_[0 1]_CLK = PCLK/8	48.2			ns	
	SPI_[0 1]_CLK = PCLK/16	0.1			μs	
	SPI_[0 1]_CLK = PCLK/32	0.19			μs	
	SPI_[0 1]_CLK = PCLK/64	0.39			μs	
	SPI_[0 1]_CLK = PCLK/128	0.77			μs	